

Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at www.onsemi.com

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild guestions@onsemi.com.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any EDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officer





April 2011



22-Bit Bi-Directional Serializer/Deserializer

Features

- · Industry smallest 22-bit Serializer/Deserializer pair
- Low power for minimum impact on battery life
 Multiple power-down modes
- 100nA in standby mode, 5mA typical operating conditions
- Highly rolled LVCMOS edge rate option to meet regulatory requirements
- Cable reduction: 25:4 or greater
- · Differential signaling:
 - --90dBm EMI when using CTL in lab conditions
 - -Minimized shielding
 - -Minimized EMI filter
 - -Minimum susceptibility to external interference
- · Up to 22 bits in either direction
- Voltage translation from 1.65V to 3.6V
- · High ESD protection: > 15kV HBM
- Parallel I/O power supply (V_{DDP}) range, 1.65V 3.6V
- · Can support Microcontroller or RGB pixel interface

Applications

- Image sensors
- · Small displays
 - LCD, cell phone, digital camera, portable gaming, printer, PDA, video camera, automotive

Description

The FIN224AC µSerDes™ is a low-power serializer/ deserializer (SerDes) that can help minimize the cost and power of transferring wide signal paths. Through the use of serialization, the number of signals transferred from one point to another can be significantly reduced. Typical reduction is 4:1 to 6:1 for unidirectional paths. For bidirectional operation, using half duplex for multiple sources, it is possible to reach signal reduction close to 10:1. Through the use of differential signaling, shielding and EMI filters can also be minimized, further reducing the cost of serialization. The differential signaling is also important for providing a noise-insensitive signal that can withstand radio and electrical noise sources. Major reduction in power consumption allows minimal impact on battery life in ultra-portable applications. It is possible to use a single PLL for most applications including bidirectional operation.

FIN224AC to FIN24AC Comparison

- · Up to 20% power reduction
- Double wide CKP pulse on FIN224AC, Mode 3
- Rolled edge rate for deserializer outputs on FIN224AC, for single display applications
- · Same voltage range
- · Same pinout and package

Ordering Information

Order Number	Operating Temperature Range	Package Description	Packing Method
FIN224ACGFX	-30 to +70°C	42-Ball, Ultra-Small Scale Ball Grid Array (USS-BGA), JEDEC MO-195, 3.5mm Wide (Slow LVCMOS Edge Rate)	Tape and Reel
FIN224ACMLX	-30 to +70°C	40-Terminal, Molded Leadless Package (MLP), Quad, JEDEC MO-220, 6mm Square (Slow LVCMOS Edge Rate)	Tape and Reel

μSerDesTM is a trademark of Fairchild Semiconductor Corporation.

Basic Concept

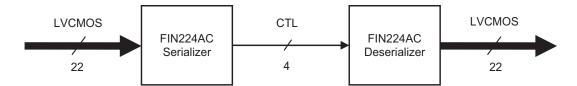


Figure 1. Conceptual Diagram

Functional Block Diagram

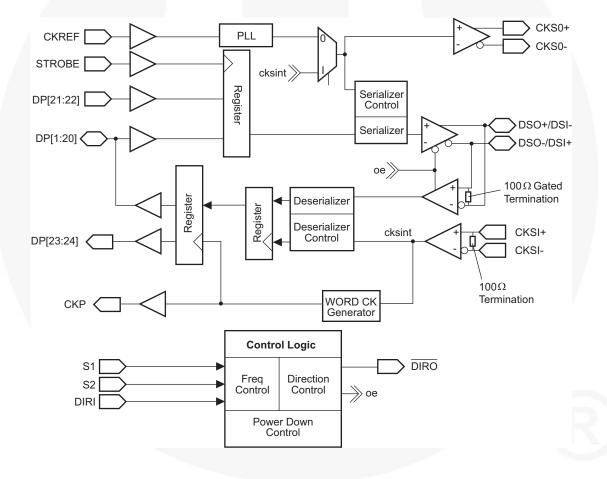


Figure 2. Block Diagram

Terminal Description

Terminal Name	I/O Type	Number of Terminals	Description of Signals
DP[1:20]	I/O	20	LVCMOS parallel I/O, Direction controlled by DIRI pin
DP[21:22]	I	2	LVCMOS parallel unidirectional inputs
DP[23:24]	0	2	LVCMOS unidirectional parallel outputs
CKREF	IN	1	LVCMOS clock input and PLL reference
STROBE	IN	1	LVCMOS strobe signal for latching data into the serializer
CKP	OUT	1	LVCMOS word clock output
DSO+ / DSI- DSO- / DSI+	DIFF-I/O	2	CTL differential serial I/O data signals ^(1.) DSO: Refers to output signal pair DSI: Refers to input signal pair DSO(I)+: Positive signal of DSO(I) pair DSO(I)-: Negative signal of DSO(I) pair
CKSI+ CKSI-	DIFF-IN	2	CTL differential deserializer input bit clock CKSI: Refers to signal pair CKSI+: Positive signal of CKSI pair CKSI-: Negative signal of CKSI pair
CKSO+ CKSO-	DIFF-OUT	2	CTL differential serializer output bit clock CKSO: Refers to signal pair CKSO+: Positive signal of CKSO pair CKSO-: Negative signal of CKSO pair
S1	IN	1	LVCMOS mode selection terminals used to select frequency range for
S2	IN	1	the reflect, CKREF
DIRI	IN	1	LVCMOS control input used to control direction of data flow: DIRI = "1" Serializer DIRI = "0" Deserializer
DIRO	OUT	1	LVCMOS control output inversion of DIRI
V_{DDP}	Supply	1	Power supply for parallel I/O and translation circuitry
V _{DDS}	Supply	1	Power supply for core and serial I/O
V_{DDA}	Supply	1	Power supply for analog PLL circuitry
GND	Supply	2	For ground signals (2 for µBGA, 1 for MLP)

Note:

The DSO/DSI serial port pins have been arranged such that if one device is rotated 180 degrees with respect to the
other device, the serial connections properly align without the need for any traces or cable signals to cross. Other
layout orientation may require that traces or cables cross.

Connection Diagrams

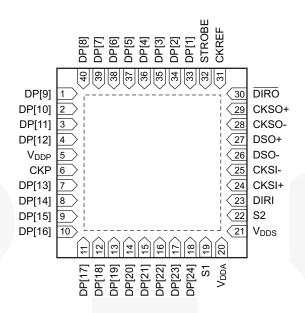


Figure 3. Terminal Assignments for MLP (Top View)

	3.	5m (.5m	GA m x nm l	4.5 Pitc	mn th)	_		-	1
		(T	op ∖	/iew)			Α	DP[9]
	1	2	3	4	5	6		В	DP[11]
Α		0	0	0	0	\circ		С	CKP
В	0	0	\circ	\circ	0	0		_	_
С		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\cap		D	DP[13]
D		\sim	\sim	\sim	\sim			Ε	DP[15]
	$\Gamma_{\bar{a}}$	-	-	-	-			F	DP[17]
Е		0	0	0	O	\circ			
F	0	\circ	0	0	0	0		G	DP[19]
G	looplus	0	0	0	0				

	Pin Assignments									
	1	2	3	4	5	6				
Α	DP[9]	DP[7]	DP[5]	DP[3]	DP[1]	CKREF				
В	DP[11]	DP[10]	DP[6]	DP[2]	STROBE	DIRO				
С	CKP	DP[12]	DP[8]	DP[4]	CKSO+	CKSO-				
D	DP[13]	DP[14]	VDDP	GND	DSO-/DSI+	DSO+/DSI-				
Е	DP[15]	DP[16]	GND	VDDS	CKSI+	CKSI-				
F	DP[17]	DP[18]	DP[21]	VDDA	S2	DIRI				
G	DP[19]	DP[20]	DP[22]	DP[23]	DP[24]	S1				

Figure 4. Terminal Assignments for µBGA (Top View)

Control Logic Circuitry

The FIN224AC has the ability to be used as a 22-bit serializer or a 22-bit deserializer. Pins S1 and S2 must be set to accommodate the clock reference input frequency range of the serializer. Table 1 shows the pin programming of these options based on the S1 and S2 control pins. The DIRI pin controls whether the device is a serializer or a deserializer. When DIRI is asserted LOW, the device is configured as a deserializer. When the DIRI pin is asserted HIGH, the device is configured as a serializer. Changing the state on the DIRI signal reverses the direction of the I/O signals and generate the opposite state signal on DIRO. For unidirectional operation the DIRI pin should be hardwired to the HIGH or LOW state and the DIRO pin should be left floating. For bi-directional operation, the DIRI of the master device is driven by the system and the DIRO signal of the master is used to drive the DIRI of the slave device.

Serializer/Deserializer with Dedicated I/O Variation

The serialization and deserialization circuitry is set up for 24 bits. Because of the dedicated inputs and outputs, only 22 bits of data are serialized or deserialized. DP[21:22] inputs to the serializer are transmitted to DP[23:24] outputs on the deserializer.

Turn-Around Functionality

The device passes and inverts the $\overline{\text{DIRI}}$ signal through the device asynchronously to the $\overline{\text{DIRO}}$ signal. Care must be taken by the system designer to ensure that no contention occurs between the deserializer outputs and the other devices on this port. Optimally the peripheral device driving the serializer should be put into a HIGH-impedance state prior to the DIRI signal being asserted. When a device with dedicated data outputs turns from a deserializer to a serializer, the dedicated outputs remain at the last logical value asserted. This value only changes if the device is once again turned around into a deserializer and the values are overwritten.

Power-Down Mode: (Mode 0)

Mode 0 is used for powering down and resetting the device. When both of the mode signals are driven to a LOW state, the PLL and references are disabled, differential input buffers are shut off, differential output buffers are placed into a HIGH-impedance state, LVCMOS outputs are placed into a HIGH-impedance state, and LVCMOS inputs are driven to a valid level internally. Additionally all internal circuitry is reset. The loss of CKREF state is also enabled to ensure that the PLL only powers-up if there is a valid CKREF signal.

In a typical application mode, signals of the device do not change states other than between the desired frequency range and the power-down mode. This allows for system-level power-down functionality to be implemented via a single wire for a SerDes pair. The S1 and S2 selection signals that have their operating mode driven to a "logic 0" should be hardwired to GND. The S1 and S2 signals that have their operating mode driven to a "logic 1" should be connected to a system-level power-down or reset signal.

Table 1. Control Logic Circuitry

Mode Number	S2	S1	DIRI	Description
0	0	0	х	Power-Down Mode
1	0	1	1	22-Bit Serializer 2MHz to 5MHz CKREF
1	0	1	0	22-Bit Deserializer
2	1	0	1	22-Bit Serializer 5MHz to 15MHz CKREF
2	1	0	0	22-Bit Deserializer
3	1	1	1	22-Bit Serializer 10MHz to 26MHz CKREF (Divide by 2 Serial Data)
J	1	1	0	22-Bit Deserializer

Serializer Operation Mode

The serializer configurations are described in the following sections. The basic serialization circuitry works essentially identically in these modes, but the actual data and clock streams differ depending on if CKREF is the same as the STROBE signal or not. When it is stated that CKREF does not equal STROBE, each signal is distinct and CKREF must be running at a frequency high enough to avoid any loss of data condition. CKREF must never be a lower frequency than STROBE.

Serializer Operation: MODE 1 or MODE 2, DIRI = 1. CKREF = STROBE

The PLL must receive a stable CKREF signal to achieve lock prior to any valid data being sent. The CKREF signal can be used as the data STROBE signal provided that data can be ignored during the PLL lock phase.

Once the PLL is stable and locked, the device can begin to capture and serialize data. Data is captured on the rising edge of the STROBE signal and serialized. When operating in serializer mode, the internal deserializer circuitry is disabled; including the serial clock, serial data input buffers, bi-directional parallel outputs, and CKP word clock. The CKP word clock is driven HIGH.

Serializer Operation: DIRI = 1, CKREF Does Not = STROBE

If the same signal is not used for CKREF and STROBE, the CKREF signal must be run at a higher frequency than the STROBE rate to serialize the data correctly. The actual serial transfer rate remains at 13 times the CKREF frequency. A data bit value of zero is sent when no valid data is present in the serial bit stream. The operation of the serializer otherwise remains the same.

The exact frequency that the reference clock needs to run at depends upon the stability of the CKREF and STROBE signal. If the source of the CKREF signal implements spread spectrum technology, the minimun frequency of the spread spectrum clock should be used in calculating the ratio of STROBE frequency to the CKREF frequency. Similarly, if the STROBE signal has significant cycle-to-cycle variation, the maximum cycle-to-cycle time needs to be factored into the selection of the CKREF frequency.

Serializer Operation: MODE 3 (S1 = S2 =1), DIRI =1. CKREF Divide by 2 Mode.

When operating in mode 3, the effective serial speed is divided by two. This mode has been implemented to accommodate cases where the reference clock frequency is high compared to the actual strobe frequency. The actual strobe frequency must be less than or equal to 50% of the CKREF frequency for this mode to work properly. This mode, in all other ways, operates the same as described in the section where CKREF does not equal STROBE.

Serializer Operation: DIRI = 1, No CKREF

A third method of serialization can be acheived by providing a free-running bit clock on the CKSI signal. This mode is enabled by grounding the CKREF signal and driving the DIRI signal HIGH. At power-up, the device is configured to accept a serialization clock from CKSI. If a CKREF is received, this device enables the CKREF serialization mode. The device remains in this mode even if CKREF is stopped. To re-enable this mode, the device must be powered down and then powered back up with a "logic 0" on CKREF.

Deserializer Operation Mode

The operation of the deserializer is dependent on the data received on the DSI data signal pair and the CKSI clock signal pair. The following sections describe the operation of the deserializer under distinct serializer source conditions. References to the CKREF and STROBE signals refer to the signals associated with the serializer device generating the serial data and clock signals that are inputs to the deserializer. When operating in deserializer mode, the internal serializer circuitry is disabled, including the parallel data input buffers. If there is a CKREF signal provided, the CKSO serial clock continues to transmit bit clocks. Upon power-up (S1 or S2 = 1), deserializer output data pins are driven LOW until valid data is passed through the deserializer.

Deserializer Operation: DIRI = 0 (Serializer Source: CKREF = STROBE)

When the DIRI signal is asserted LOW, the device is configured as a deserializer. Data is captured on the

serial port and deserialized through use of the bit clock sent with the data.

Deserializer Operation: DIRI = 0 (Serializer Source: CKREF Does Not = STROBE)

The logical operation of the deserializer remains the same if the CKREF is equal in frequency to the STROBE or at a higher frequency than the STROBE. The actual serial data stream presented to the deserializer is different because it has non-valid data bits sent between words. The duty cycle of CKP varies based on the ratio of the frequency of the CKREF signal to the STROBE signal. The frequency of the CKP signal is equal to the STROBE frequency. In modes 1 and 2, the CKP LOW time equals half of the CKREF period of the serializer. In mode 3, the CKP LOW is equal to the CKREF period. The CKP HIGH time is approximately equal to the STROBE period, minus the CKP LOW time.

LVCMOS Data I/O

The LVCMOS input buffers have a nominal threshold value equal to half V_{DD} . The input buffers are only operational when the device is operating as a serializer. When the device is operating as a deserializer, the inputs are gated off to conserve power.

The LVCMOS 3-STATE output buffers are rated for a source / sink current of approximately 0.5mA at 1.8V. The outputs are active when the DIRI signal and either S1 or S2 is asserted HIGH. When the DIRI signal and either S1 or S2 is asserted LOW, the bi-directional LVC-MOS I/Os is in a HIGH-Z state. Under purely capacitive load conditions, the output swings between GND and $V_{DDP}.$ When S1 or S2 initially transitions HIGH, the initial state of the deserializer LVCMOS outputs is zero.

Unused LVCMOS input buffers must be either tied off to a valid logic LOW or a valid logic HIGH level to prevent static current draw due to a floating input. Unused LVC-MOS output should be left floating. Unused bi-directional pins should be connected to GND through a high-value resistor. If a FIN224AC device is configured as an unidirectional serializer, unused data I/O can be treated as unused inputs. If the FIN224AC is hardwired as a deserializer, unused data I/O can be treated as unused outputs.

Application Mode Diagrams

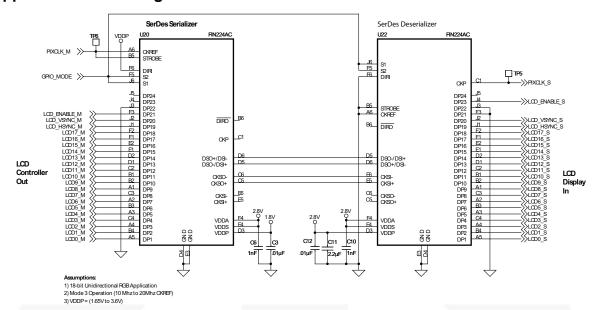


Figure 5. FIN224AC RGB

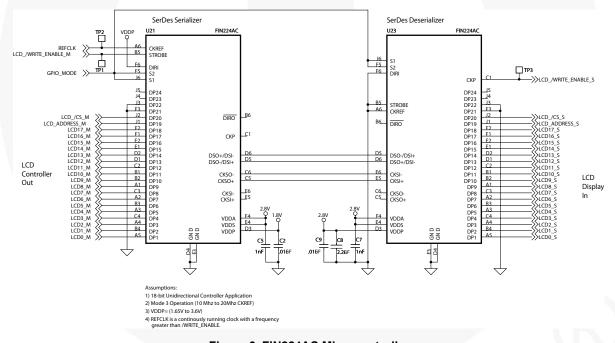


Figure 6. FIN224AC Microcontroller

Flex Circuit Design Guidelines

The serial I/O information is transmitted at a high serial rate. Care must be taken implementing this serial I/O flex cable. The following best practices should be used when developing the flex cabling or Flex PCB:

Keep all four differential wires the same length.

Allow no noisy signals over or near differential serial wires. Example: No LVCMOS traces over differential wires.

Use only one ground plane or wire over the differential serial wires. Do not run ground over top and bottom.

Do not place test points on differential serial wires.

Use differential serial wires a minimum of 2cm away from the antenna.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Min.	Max.	Unit	
V _{DD}	Supply Voltage	-0.5	+4.6	V	
	ALL Input/Output Voltage	-0.5	+4.6	V	
I _{OS}	CTL Output Short-Circuit Duration	Continuous			
T _{STG}	Storage Temperature Range	-65	+150	°C	
T _J	Maximum JunctionTemperature		+150	°C	
T _L	Lead Temperature (Soldering 4 Seconds)		+260	°C	
	IEC61000-4-2		15.0		
ESD	Human Body Model, JESD22-A114, Serial I/O Pin		8.0	kV	
ESD	Human Body Model, JESD22-A114, All Pins		2.5	KV	
	Charged Device Model, JESD22-C101		2.0		

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Min.	Max.	Unit
V_{DDA}, V_{DDS}	Supply Voltage	2.5	3.3	V
V_{DDP}	Supply Voltage	1.65	3.60	V
T _A	Operating Temperature ^(2.)	-30	+70	°C
V _{DDA-PP}	Supply Noise Voltage		100	mV_{PP}

Note

Absolute maximum ratings are DC values beyond which the device may be damaged or have its useful life impaired.
The datasheet specification should be met, without exception, to ensure that the system design is reliable over its
power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside
datasheet specifications.

DC Electrical Characteristics

Values are for over-supply voltage and operating temperature ranges, unless otherwise specified. Typical values are given for V_{DD} = 2.775V and T_A = 25°C. Positive current values refer to the current flowing into the device and negative values refer to the current flowing out of the pins. Voltages are referenced to GROUND unless otherwise specified (except ΔV_{OD} and V_{OD}).

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
LVCMOS	1/0			'			
V_{IH}	Input High Voltage			0.65 x V _{DDP}		V _{DDP}	
V _{IL}	Input Low Voltage			GND		0.35 x V _{DDP}	٧
			$V_{DDP} = 3.3 \pm 0.30$				
V_{OH}	Output High Voltage	I _{OH} = 2.0mA	V _{DDP} = 2.5±-0.20	0.75 x V _{DDP}			٧
			V _{DDP} = 1.8±0.18				
			V _{DDP} = 3.3±0.30				
V_{OL}	Output Low Voltage	I _{OL} = 2.0mA	$V_{DDP} = 2.5 \pm 0.20$			0.25 x V _{DDP}	V
			$V_{DDP} = 1.8 \pm 0.18$				
I _{IN}	Input Current	$V_{IN} = 0V \text{ to } 3.$	6V	-5.0	V.	5.0	μA
DIFFERE	NTIAL I/O						
I _{ODH}	Output HIGH source current	V _{OS} = 1.0V			-1.75		mA
I _{ODL}	Output LOW sink current	V _{OS} = 1.0V			0.950		mA
1	Short-Circuit Output	V _{OUT} = 0V	Driver Enabled				mA
los	Current		Driver Disabled			±5	μA
I _{OZ}	Disabled Output Leakage Current	CKSO, DSO = S2 = S1 = 0V	= 0V to V _{DDS}		±1	±5	μA
I _{TH}	Differential Input Threshold High Current			50			μA
I _{TL}	Differential Input Threshold Low Current					-50	μA
I _{IZ}	Disabled Input Leakage Current	CKSI, DSI = 0 S2 = S1 = 0V	OV to V _{DDS}		±1	±5	μA
I _{IS}	Short-Circuit Input Current	V _{OUT} = V _{DDS}					mA
V _{ICM}	Input Common Mode Range	V _{DDS} = 2.775	±5%	0.5		V _{DDS-1}	V
R _{TRM}	CKSI, DS Internal Receiver Termination Resistor	V _{ID} = 50mV, V CKSI ⁺ – CKS	V _{IC} = 925mV, DIRI = 0 SI ⁻ = V _{ID}		100		Ω

Power Supply Currents

Typical values are given for V_{DD} = 2.775V and T_A = 25°C. Positive current values refer to the current flowing into the device and negative values refer to the current flowing out of the pins. Voltages are referenced to GROUND unless otherwise specified (except ΔV_{OD} and V_{OD}).

Symbol	Parameter	Test Con	ditions		Min.	Тур.	Max.	Unit
IDDA1	VDDA Serializer Static Supply Current	All DP and Control I NOCKREF, S2 = 0,				450		μA
IDDA2	VDDA Deserializer Static Supply Current	All DP and Control I NOCKREF, S2 = 0,				550		μA
IDDS1	VDDS Serializer Static Supply Current	All DP and Control I NOCKREF, S2 = 0,		4		mA		
IDDS2	VDDS Deserializer Static Supply Current		All DP and Control Inputs at 0V or NOCKREF, S2 = 0, S1 = 1, DIR = 0					mA
IDD_PD	VDD Power-Down Supply Current IDD_PD = IDDA	S1 = S2 = 0 All Input		0.1		μA		
			S2 = 0	1.2MHz		9		
			S1 = 1	5MHz		14		- mA
IDD SED1	26:1 Dynamic Serializer Power Supply Current	CKREF = STROBE		5MHz		9		
IDD_SERT	IDD_SER1 = IDDA+IDDS+IDDP	DIRI = H	S1 = 0	15MHz		17		
			S2 = 1	10MHz		9		
			S1 = 1	26MHz		16		
			S2 = 0 S1 = 1	2MHz		5		
				5MHz		6		
IDD DES1	26:1 Dynamic Deserializer Power Supply Current	CKREF = STROBE	S2 = 1	5MHz		4		mA
IDD_DEST	IDD_DES1 = IDDA+IDDS+IDDP	DIRI = L	S1 = 0	15MHz		5		IIIA
			S2 = 1	10MHz		7		
			S1 = 1	26MHz		11		
				2MHz		8		
IDD SEBS	26:1 Dynamic Serializer Power Supply Current	NO CKREF STROBE Active	5MHz		8		mA	
IDD_SER2	IDD_SES2 = IDDA+IDDS+IDDP	CKSI = 15x STROB	10MHz		10			
			15MI			12		

AC Electrical Characteristics

Characteristics at recommended over-supply voltage and operating temperature ranges, unless otherwise specified. Typical values are given for V_{DD} = 2.775V and T_A = 25°C. Positive current values refer to the current flowing into device and negative values means current flowing out of the pins. Voltages are referenced to GROUND unless otherwise specified (except ΔV_{OD} and V_{OD}).

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
Serializer	Input Operating Conditions					1	
			S2=0 S1=1	200		500	
t_{TCP}	CKREF Clock Period (2MHz – 26MHz)	CKREF = STROBE Figure 7.	S2=1 S1=0	66		200	ns
	(ZIVII IZ — ZOIVII IZ)	riguic 7.	S2=1 S1=1	38.46		100.00	
f _{REF}	CKREF Frequency Relative to STROBE	CKREF does not = STROBE	S2=0 S1=1	2.25 x f _{STROBE}			MHz
t _{CPWH}	CKREF Clock High Time		1	0.2	0.5		Т
t _{CPWL}	CKREF Clock Low Time			0.2	0.5		Т
t _{CLKT}	LVCMOS Input Transition Time	Figure 9.				90.0	ns
t _{SPWH}	STROBE Pulse Width HIGH/LOW	Figure 9.		(Tx4)/26		(Tx22)/26	ns
			S2=0 S1=1	52		130	
f_{MAX}	Maximum Serial Data Rate	CKREF x 26	S2=1 S1=0	130		390	Mb/s
			S2=1 S1=1	260		676	
t _{STC}	DP _(n) Setup to STROBE	DIRI = 1		2.5			ns
t _{HTC}	DP _(n) Hold to STROBE	DINI = 1		2.0			ns
Serializer A	C Electrical Characteristics						
t _{TCCD}	Transmitter Clock Input to Clock Output Delay	CKREF = STROBE		33a+1.5		35a+6.5	ns
t _{SPOS}	CKSO Position Relative to DS ^(3.)			-50		250	ps
PLL AC Ele	ectrical Characteristics						
t _{TPLLS0}	Serializer Phase Lock Loop Stabilization Time	Figure 11.				200	μs
t _{TPLLD0}	PLL Disable Time Loss of Clock	Figure 12.				30	μs
t _{TPLLD1}	PLL Power-Down Time ^(4.)	Figure 13.				20	ns
Deserialize	r Input Operating Conditions	1					
t _{S_DS}	Serial Port Setup Time, DS-to-CKSI ^(5.)			1.4			ns
t _{H_DS}	Serial Port Hold Time, DS-to-CKS ^(5.)			-250			ps
Deserialize	r AC Electrical Characteristics						
t _{RCOP}	Deserializer Clock Output (CKP OUT) Period ^(6.)	Figure 10.		50		500	ns
t _{RCOL}	CKP OUT Low Time ^(6.)	(Rising Edge STROE	BE) Serializer	13a-3		13a+3	ns
t _{RCOH}	CKP OUT High Time	source STROBE = CKREF Figure 10.		13a-3		13a+3	ns
t _{PDV}	Data Valid to CKP LOW	(Rising Edge STROBE) Figure 10.		8a-6		8a+1	ns
t _{ROLH}	Output Rise Time (20% to 80%)	C _L = 8pF Figure 7.			18		ns
t _{ROHL}	Output Fall Time (20% to 80%)	C _L = 8pF Figure 7.			18		ns

Notes:

- 3. Skew is measured from either the rising or falling edge of CKSO clock to the rising or falling edge of data (DSO). Signals are edge aligned. Both outputs should have identical load conditions for this test to be valid.
- 4. The power-down time is a function of the CKREF frequency prior to CKREF being stopped HIGH or LOW and the state of the S1/S2 mode pins. The specific number of clock cycles required for the PLL to be disabled varies dependent upon the operating mode of the device.
- 5. Signals are transmitted from the serializer source synchronously. Note that, in some cases, data is transmitted when the clock remains at a HIGH state. Skew should only be measured when data and clock are transitioning at the same time. Total measured input skew would be a combination of output skew from the serializer, load variations, and ISI and jitter effects.
- 6. **a = (1/f)/13)** Rising edge of CKP appears approximately 13 bit times after the falling edge of the CKP output. Falling edge of CKP occurs approximately eight bit times after a data transition or six bit times after the falling edge of CKSO. Variation of the data with respect to the CKP signal is due to internal propagation delay differences of the data and CKP path and propagation delay differences on the various data pins. Note that if the CKREF is not equal to STROBE for the serializer, the CKP signal does not maintain a 50% duty cycle. The low time of CKP remains 13 bit times.

Control Logic Timing Controls

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
t _{PHL_DIR} , t _{PLH_DIR}	Propagation Delay DIRI-to-DIRO	DIRI LOW-to-HIGH or HIGH-to-LOW			17	ns
t _{PLZ} , t _{PHZ}	Propagation Delay DIRI-to-DP	DIRI LOW-to-HIGH			25	ns
t _{PZL} , t _{PZH}	Propagation Delay DIRI-to-DP	DIRI HIGH-to-LOW			25	ns
t _{PLZ} , t _{PHZ}	Deserializer Disable Time: S0 or S1 to DP	DIRI = 0, S1(2) = 0 and S2(1) = LOW-to-HIGH, Figure 14.			25	ns
t _{PZL} , t _{PZH}	Deserializer Enable Time: S0 or S1 to DP	DIRI = 0, ^(7.) S1(2) = 0 and S2(1) = LOW-to-HIGH Figure 14.			2	μs
t _{PLZ} , t _{PHZ}	Serializer Disable Time: S0 or S1 to CKSO, DS	DIRI = 1, S1(2) = 0 and S2(1) = HIGH-to-LOW, Figure 13.			25	ns
t _{PZL} , t _{PZH}	Serializer Enable Time: S0 or S1 to CKSO, DS	DIRI = 1, S1(2) and S2(1) = LOW-to-HIGH, Figure 13.			65	ns

Note:

Capacitance

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
C _{IN}	Capacitance of Input Only Signals, CKREF, STROBE, S1, S2, DIRI	DIRI = 1, S1 = S2 = 0, V _{DD} = 2.5V		2		pF
C _{IO}	Capacitance of Parallel Port Pins DP _{1:12}	DIRI = 1, S1 = S2 = 0, V _{DD} = 2.5V		2		pF
C _{IO-DIFF}	Capacitance of Differential I/O Signals	DIRI = 0, S1 = S2 = 0, V _{DD} = 2.775V		2		pF

^{7.} Deserializer Enable Time includes the time required for internal voltage and current references to stabilize. This time is significantly less than the PLL Lock Time and therefore does not limit overall system startup time.

AC Loading and Waveforms

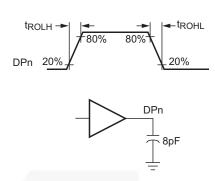


Figure 7. LVCMOS Output Load and Transition Times

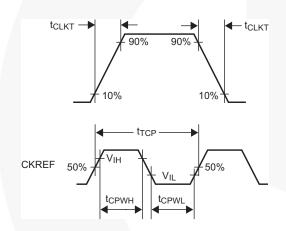
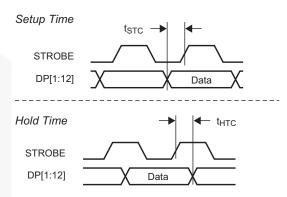
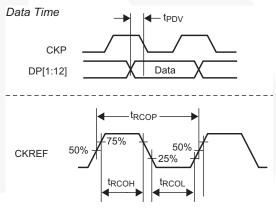


Figure 9. LVCMOS Clock Parameters



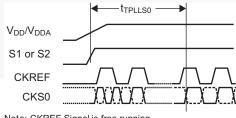
Setup: MODE0 = "0" or "1", MODE1 = "1", SER/\overline{DES} = "1"

Figure 8. Serial Setup and Hold Times



Setup: EN_DES = "1", CKSI and DSI are valid signals

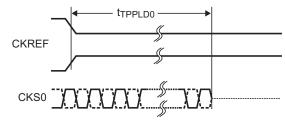
Figure 10. Deserializser Data Valid Window Time and Clock Output Parameters



Note: CKREF Signal is free running.

Figure 11. Serializer PLL Lock Time

AC Loading and Waveforms (Continued)



Note: CKREF Signal can be stopped either High or LOW

Figure 12. PLL Loss of Clock Disable Time

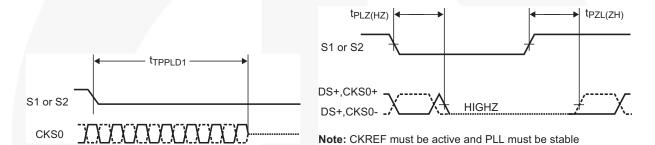
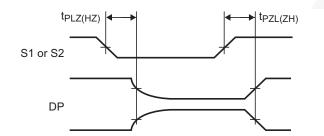


Figure 13. PLL Power-Down Time

Figure 14. Serializer Enable and Disable Time



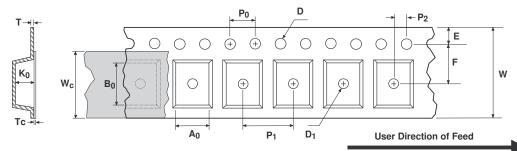
Note: If S1(2) transitioning then S2(1) must = 0 for test to be valid

Figure 15. Deserializer Enable and Disable Times

Tape and Reel Specification

MLP Embossed Tape Dimension

Dimensions are in millimeters.

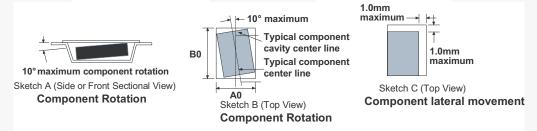


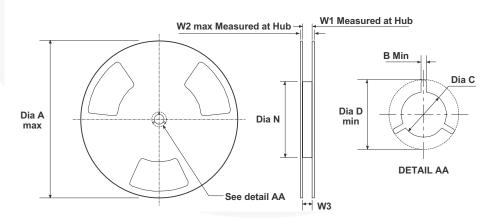
Package	A ₀ ±0.1	B ₀ ±0.1	D ±0.05	D ₁ Min.	E ±0.1	F ±0.1	K ₀ ±0.1	P ₁ Typ.	P ₀ Typ.	P ₂ ±0/05	T Typ.	T _C ±0.005	W ±0.3	W _C Typ.
5 x 5	5.35	5.35	1.55	1.50	1.75	5.50	1.40	8.00	4.00	2.00	0.30	0.07	12.00	9.30
6 x 6	6.30	6.30	1.55	1.50	1.75	5.50	1.40	8.00	4.00	2.00	0.30	0.07	12.00	9.30

Ao, Bo, and Ko dimensions are determined with respect to the EIA/JEDEC RS-481 rotational and lateral movement requirements (see sketches A, B, and C).

Shipping Reel Dimension

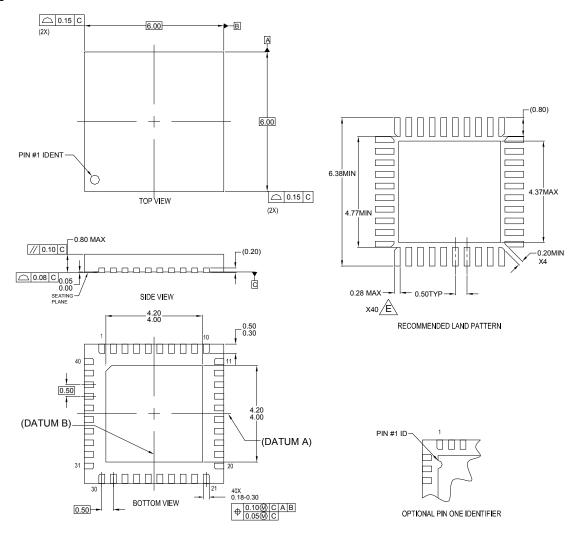
Dimensions are in millimeters.





Tape Width	Dia A Max.	Dim B Min.	Dia C +0.5/-0.2	Dia D Min.	Dim N Min.	Dim W1 +2.0/–0	Dim W2 Max.	Dim W3 (LSL-USL)
8	330.0	1.5	13.0	20.2	178.0	8.4	14.4	7.9 ~ 10.4
12	330.0	1.5	13.0	20.2	178.0	12.4	18.4	11.9 ~ 15.4
16	330.0	1.5	13.0	20.2	178.0	16.4	22.4	15.9 ~ 19.4

Physical Dimensions



NOTES:

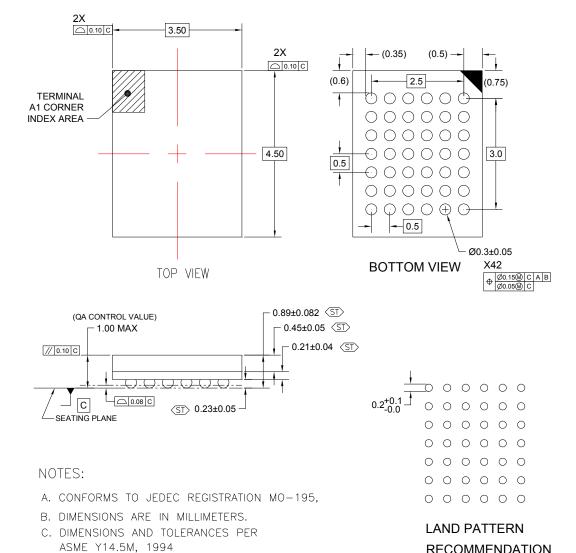
- A. CONFORMS TO JEDEC REGISTRATION MO-220, VARIATION WJJD-2 WITH EXCEPTION THAT THIS IS A SAWN VERSION...
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.
- D. LAND PATTERN PER IPC SM-782.
- E. WIDTH REDUCED TO AVOID SOLDER BRIDGING.
- F. DIMENSIONS ARE NOT INCLUSIVE OF BURRS, MOLD FLASH, OR TIE BAR PROTRUSIONS.
- G. DRAWING FILENAME: MKT-MLP40Arev3.

Figure 16. 40-Terminal, Molded Leadless Package (MLP), Quad, JEDEC MO0220, 6mm Square

Package drawings are provided as a service to customers considering Fairchild components. Drawings may change in any manner without notice. Please note the revision and/or date on the drawing and contact a Fairchild Semiconductor representative to verify or obtain the most recent revision. Package specifications do not expand the terms of Fairchild's worldwide terms and conditions, specifically the warranty therein, which covers Fairchild products.

Always visit Fairchild Semiconductor's online packaging area for the most recent package drawings: http://www.fairchildsemi.com/packaging/

Physical Dimensions (Continued)



D. STATISTICAL TOLERANCING FOR REFERENCE
REFER TO MAX DIMENSION FOR QA INSPECTION

E. LAND PATTERN RECOMENDATION PER IPC-7351 TABLE14-15 LAND PATTERN NAME PER TABLE 3-15: BGA50P+6X7-42

BGA42ArevB

Figure 17. 42-Ball, Ultra Small Scale Ball Grid Array (USS-BGA), JEDEC MO-195, 3.5mm Wide

Note: Click here for tape and reel specifications, available at:

http://www.fairchildsemi.com/products/analog/packaging/bga42.html.

Package drawings are provided as a service to customers considering Fairchild components. Drawings may change in any manner without notice. Please note the revision and/or date on the drawing and contact a Fairchild Semiconductor representative to verify or obtain the most recent revision. Package specifications do not expand the terms of Fairchild's worldwide terms and conditions, specifically the warranty therein, which covers Fairchild products.

Always visit Fairchild Semiconductor's online packaging area for the most recent package drawings:

http://www.fairchildsemi.com/packaging/





TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

The Power Franchise® AccuPower™ F-PESTM Power-SPM™ The Right Technology for Your Success™ Auto-SPM™ FRFFT[®] PowerTrench® AX-CAP™* Global Power Resource^s PowerXS™ Wer franchise Green FPS™ Programmable Active Droop™ Build it Now™ Green FPS™ e-Series™ CorePLUS™ TinyBoost™ QS™ G max™ CorePOWER™ TinyBuck™ GTOM Quiet Series™ CROSSVOLT" TinyCalc™ IntelliMAX™ RapidConfigure™ TinyLogic® ISOPLANAR™ Current Transfer Logic™ TINY OPTO** DEUXPEED' MegaBuck™ TinyPower™ Saving our world, 1mW/W/kW at a time™ Dual Cool™ MICROCOUPLER™ TinyPV⁄M™ SignalWise™ EcoSPARK® MicroFET™ TinyWire™ SmartMax™ EfficientMa×™ MicroPak™ SMART START™ TriFault Detect™ **ESBC™** MicroPak2™ TRUECURRENT®* SPM® MillerDrive™ μSerDes™ STEALTH™ MotionMax™ SuperFET Motion-SPM™ SuperSOT**3 Fairchild Semiconductor® mWSaver™ SuperSOTM-6 UHC FACT Quiet Series™ OptoHiT™ FACT® SuperSOT™-8 Ultra FRFET™ OPTOLOGIC® SupreMOS® UniFET™ OPTOPLANAR[®] SyncFET™ FastvCore™ **VCXTM** Sync-Lock™ VisualMax™ FETBench™ SYSTEM ... XSTM FlashWriter®*

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user

PDP SPM™

A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition					
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.					
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.					
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.					
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.					

Rev. 153

^{*} Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

ON Semiconductor and in are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdt/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor and see any inability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and ex

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81–3–5817–1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for LVDS Interface IC category:

Click to view products by ON Semiconductor manufacturer:

Other Similar products are found below:

FIN224ACMLX 8T49N2083NLGI# MAX9135GHJ+ MS1224 SN65LVP16DRFT SN65MLVD200D MAX9176EUB+
DS90LV047ATMX/NOPB DS90LV018ATM DS90LT012AHMF DS90LV049TMT DS90LV047ATM DS90LV032ATMTC
DS90C383MTDX/NOPB DS90C383MTD DS90LV031ATMTC DS90C402M SN65LVDS051PWRQ1 DS90C387VJDXNOPB
SN65LVDT32BDR ADN4665ARUZ ADN4666ARUZ ADN4666ARZ-REEL7 ADN4692EBRZ ADN4693EBRZ ADN4697EBRZ
ADN4695EBRZ ADN4665ARZ ADN4666ARZ ADN4667ARZ ADN4667ARZ-REEL7 ADN4668ARZ ADN4670BSTZ ADN4670BCPZ
ADN4661BRZ ADN4663BRZ-REEL7 ADN4694EBRZ-RL7 ADN4662BRZ-REEL7 ADN4662BRZ ADN4691EBRZ ADN4694EBRZ
ADN4690EBRZ ADN4661BRZ-REEL7 MAX9113ESA+ GM8285BGA MAX9113ESA+T MAX9111ESA+T MAX9112ESA+T
MAX9122EUE+T MAX9174EUB+T